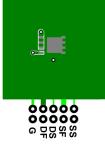


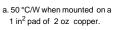
FDMS86101A N-Channel Shielded Gate PowerTrench[®] MOSFET

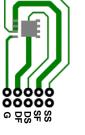
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					I
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		71		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			800	nA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
	cteristics			1	1	1
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	2.0	3.1	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{I}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-9		mV/°C
5		V _{GS} = 10 V, I _D = 13 A		6.3	8	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 9.5 \text{ A}$		8.0	13.5	mΩ
20(01)		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 13 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$		10.3	13.1	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 13 A		53		S
C _{iss} C _{oss} C _{rss}	Input Capacitance Output Capacitance Reverse Transfer Capacitance	$V_{DS} = 50 V, V_{GS} = 0 V,$ f = 1 MHz		3095 460 15	4120 615 25	pF pF pF
		f = 1 MHz				
R _g	Gate Resistance		0.1	1.6	3.3	Ω
Switching	Characteristics			[]		1
t _{d(on)}	Turn-On Delay Time			19	35	ns
t _r	Rise Time	V_{DD} = 50 V, I _D = 13 A, V _{GS} = 10 V, R _{GEN} = 6 Ω		5.4	11	ns
t _{d(off)}	Turn-Off Delay Time			27	44	ns
t _f	Fall Time			4	10	ns
Qg	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		42	58	nC
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 50 V,$		22	31	nC
Q _{gs}	Gate to Source Charge	I _D = 13 A		13.5		nC
Q _{gd}	Gate to Drain "Miller" Charge			6.2		nC
Drain-Soເ	urce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.1 A$ (Note 2)		0.74	1.2	v
50		$V_{GS} = 0 V, I_S = 13 A$ (Note 2)		0.81	1.3	
t _{rr}	Reverse Recovery Time	I _F = 13 A, di/dt = 100 A/μs		64	102	ns
Q _{rr}	Reverse Recovery Charge	F,		102	164	nC





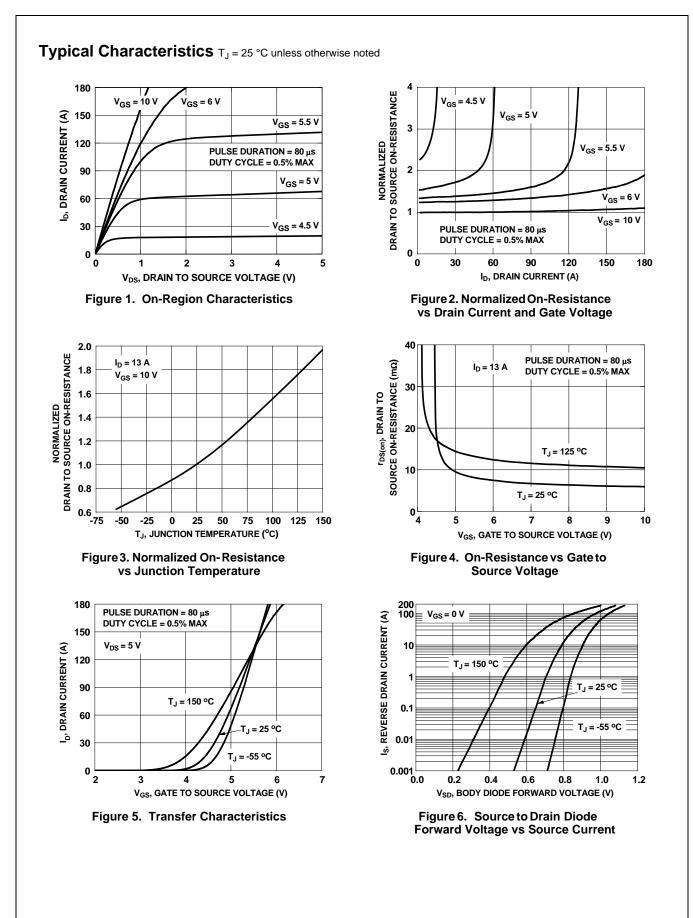


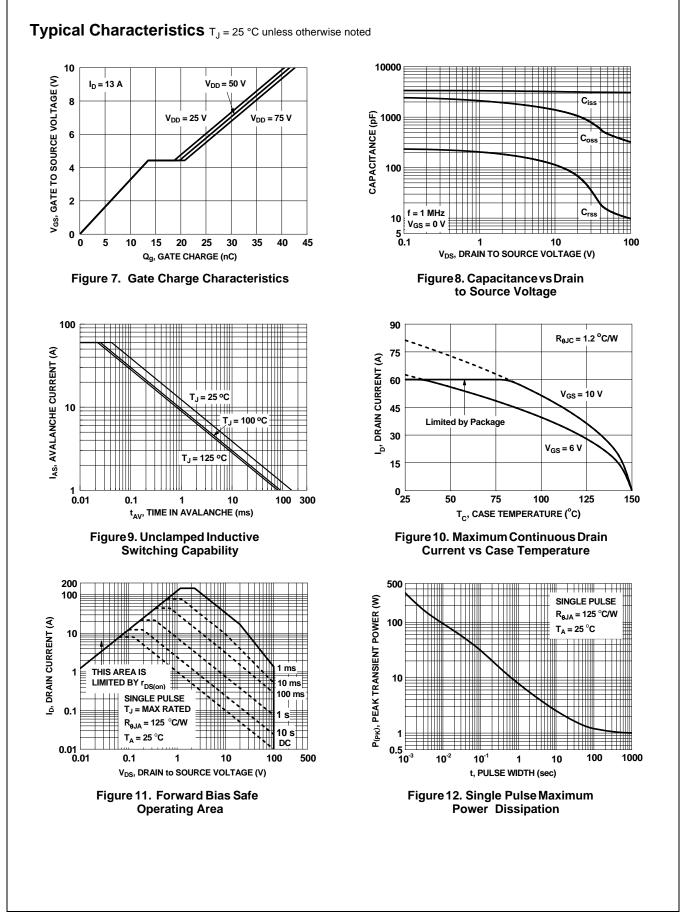
b. 125 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 $\mu \text{s},$ Duty cycle < 2.0%.

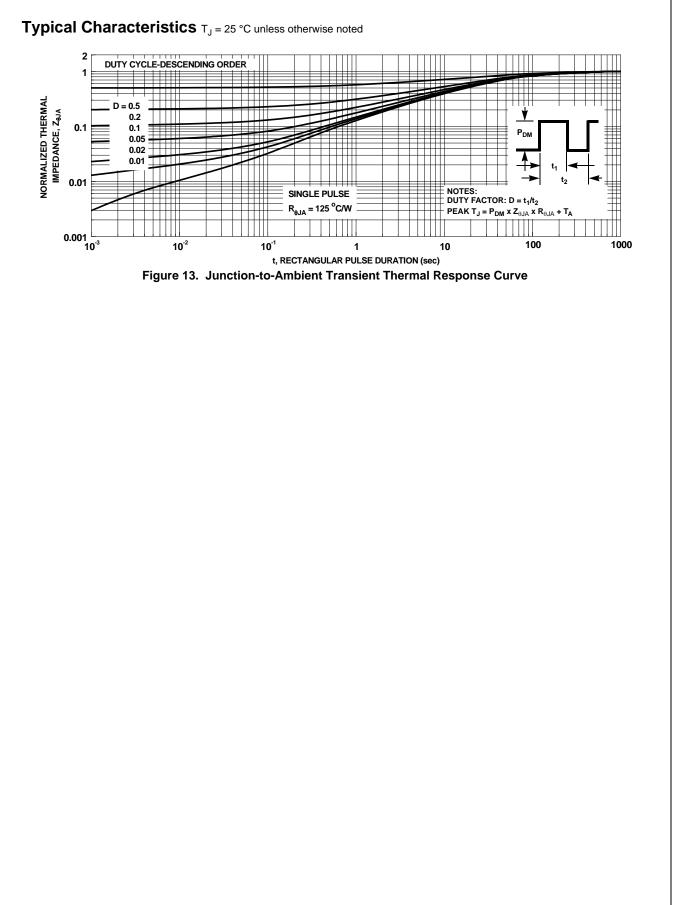
3. E_{AS} 486 mJ is based on starting T_J = 25 °C, L = 3 mH, I_{AS} = 18 A, V_{DD} = 100 V, V_{GS} = 10 V. 100% test at L = 0.1 mH, I_{AS} = 51 A.

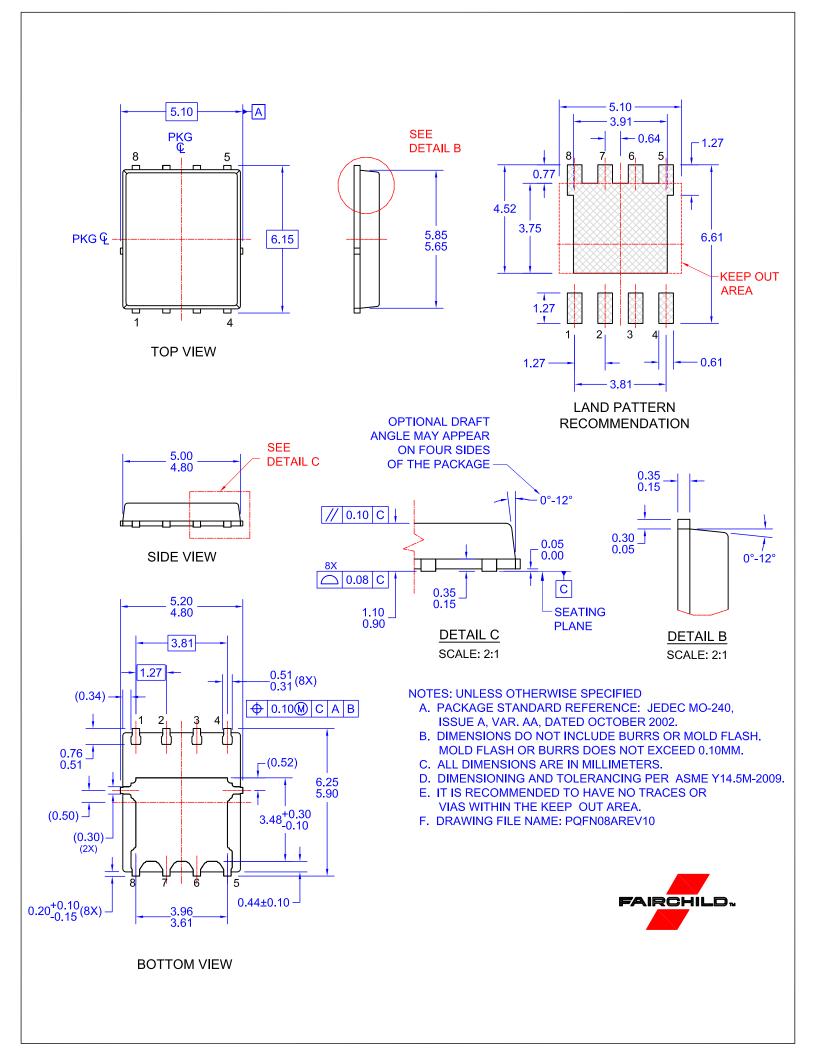






FDMS86101A N-Channel Shielded Gate PowerTrench[®] MOSFET







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